

Soft Recovery Diode

Type M0139S/R#120 to M0139S/R#180

Absolute Maximum Ratings

| | VOLTAGE RATINGS | MAXIMUM LIMITS | UNITS |
|-----------|---|----------------|-------|
| V_{RRM} | Repetitive peak reverse voltage, (note 1) | 1200-1800 | V |
| V_{RSM} | Non-repetitive peak reverse voltage, (note 1) | 1300-1900 | V |

| | OTHER RATINGS | MAXIMUM LIMITS | UNITS |
|---------------|---|-------------------|-------------|
| $I_{F(AV)M}$ | Maximum average forward current, $T_{sink}=55^{\circ}C$, (note 2) | 139 | A |
| $I_{F(AV)M}$ | Maximum average forward current. $T_{sink}=100^{\circ}C$, (note 2) | 58 | A |
| $I_{F(RMS)}$ | Nominal RMS forward current, $T_{sink}=25^{\circ}C$, (note 2) | 288 | A |
| $I_{F(d.c.)}$ | D.C. forward current, $T_{sink}=25^{\circ}C$, (note 3) | 219 | A |
| I_{FSM} | Peak non-repetitive surge $t_p=10ms$, $V_{RM}=60\%V_{RRM}$, (note 3) | 2450 | A |
| I_{FSM2} | Peak non-repetitive surge $t_p=10ms$, $V_{RM}\leq 10V$, (note 3) | 2695 | A |
| I^2t | I^2t capacity for fusing $t_p=10ms$, $V_{RM}=60\%V_{RRM}$, (note 3) | 30×10^3 | A^2s |
| I^2t | I^2t capacity for fusing $t_p=10ms$, $V_{RM}\leq 10V$, (note 3) | 36.5×10^3 | A^2s |
| $T_{j\ op}$ | Operating temperature range | -40 to +125 | $^{\circ}C$ |
| T_{stg} | Storage temperature range | -40 to +150 | $^{\circ}C$ |

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) single phase; 50Hz, 180° half-sinewave.
- 3) Half-sinewave, $125^{\circ}C$ T_j initial.

Characteristics

| | PARAMETER | MIN. | TYP. | MAX. | TEST CONDITIONS (Note 1) | UNITS |
|-------------------|--------------------------------------|------|------|------|---|-------|
| V _{FM} | Maximum peak forward voltage | - | - | 1.60 | I _{FM} =280A | V |
| V _{T0} | Threshold voltage | - | - | 1.24 | | V |
| r _T | Slope resistance | - | - | 1.28 | | mΩ |
| I _{RRM} | Peak reverse current | - | - | 20 | Rated V _{RRM} | mA |
| Q _{ra} | Recovered charge, 50% Chord | | | 90 | I _{FM} =1000A, t _p =500μs, di/dt=100A/μs, V _r =50V, 50% Chord. | μC |
| R _{thJC} | Thermal resistance, junction to case | - | - | 0.30 | | K/W |
| T | Mounting torque | 11 | - | 14 | | Nm |
| W _t | Weight | - | 85 | - | | g |

Notes:-

- 1) Unless otherwise indicated T_j=125°C.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

| Voltage Grade | V _{RRM} (V) | V _{RSM} (V) | V _R dc (V) |
|---------------|-------------------------|-------------------------|--------------------------|
| 12 | 1200 | 1300 | 810 |
| 18 | 1800 | 1900 | 1350 |

2.0 De-rating Factor

A blocking voltage de-rating factor of 0.13% per °C is applicable to this device for T_j below 25°C.

3.0 ABCD Constants

These constants (applicable only over current range of V_F characteristic in Figure 1) are the coefficients of the expression for the forward characteristic given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

where I_F = instantaneous forward current.

4.0 Reverse recovery ratings

(i) Q_{rr} is based on 50% I_{rm} chord as shown in Fig.(a) below.



(ii) Q_{rr} is based on a 150µs integration time.

i.e.

$$Q_{rr} = \int_0^{150\mu s} i_{rr} \cdot dt$$

(iii)

$$K \text{ Factor} = \frac{t_1}{t_2}$$

5.0 Reverse Recovery Loss

The following procedure is recommended for use where it is necessary to include reverse recovery loss.

From waveforms of recovery current obtained from a high frequency shunt (see Note 1) and reverse voltage present during recovery, an instantaneous reverse recovery loss waveform must be constructed. Let the area under this waveform be E joules per pulse. A new sink temperature can then be evaluated from:

$$T_{SINK} = T_{J(MAX)} - E \cdot [k + f \cdot R_{thJK}]$$

Where $k = 0.2314$ ($^{\circ}\text{C/W}$)/s

E = Area under reverse loss waveform per pulse in joules (W.s.)

f = Rated frequency in Hz at the original sink temperature.

R_{thJK} = d.c. thermal resistance ($^{\circ}\text{C/W}$)

The total dissipation is now given by:

$$W_{(tot)} = W_{(original)} + E \cdot f$$

NOTE 1 - Reverse Recovery Loss by Measurement

This device has a low reverse recovered charge and peak reverse recovery current. When measuring the charge, care must be taken to ensure that:

(a) AC coupled devices such as current transformers are not affected by prior passage of high amplitude forward current.

(b) A suitable, polarised, clipping circuit must be connected to the input of the measuring oscilloscope to avoid overloading the internal amplifiers by the relatively high amplitude forward current signal.

(c) Measurement of reverse recovery waveform should be carried out with an appropriate critically damped snubber, connected across diode anode to cathode. The formula used for the calculation of this snubber is shown below:

$$R^2 = 4 \cdot \frac{V_r}{C_s \cdot di/dt}$$

Where: V_r = Commutating source voltage

C_s = Snubber capacitance

R = Snubber resistance

6.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

7.0 Computer Modelling Parameters

7.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$

Where $V_{T0} = 1.24V$, $r_T = 1.28m\Omega$

ff = form factor (normally unity for fast diode applications)

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j(MAX)} - T_K$$

7.2 Calculation of V_F using ABCD Coefficients

The forward characteristic I_F Vs V_F , on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, and D forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given in this report for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

| | 25°C Coefficients | 125°C Coefficients |
|---|---------------------------|---------------------------|
| A | 0.237145 | -0.922256 |
| B | 0.2255735 | 0.5643498 |
| C | 0.63392×10^{-3} | 1.189357×10^{-3} |
| D | -4.89596×10^{-3} | -0.05985509 |

8.0 Frequency Ratings

The curves illustrated in figures 4 to 12 are for guidance only and are superseded by the maximum ratings shown on page 1.

9.0 Square wave ratings

These ratings are given for load component rate of rise of forward current of 100 and 500 A/ μ s.

10.0 Duty cycle lines

The 100% duty cycle is represented on all the ratings by a straight line. Other duties can be included as parallel to the first.

Curves

Figure 1 – Forward characteristics of Limit device

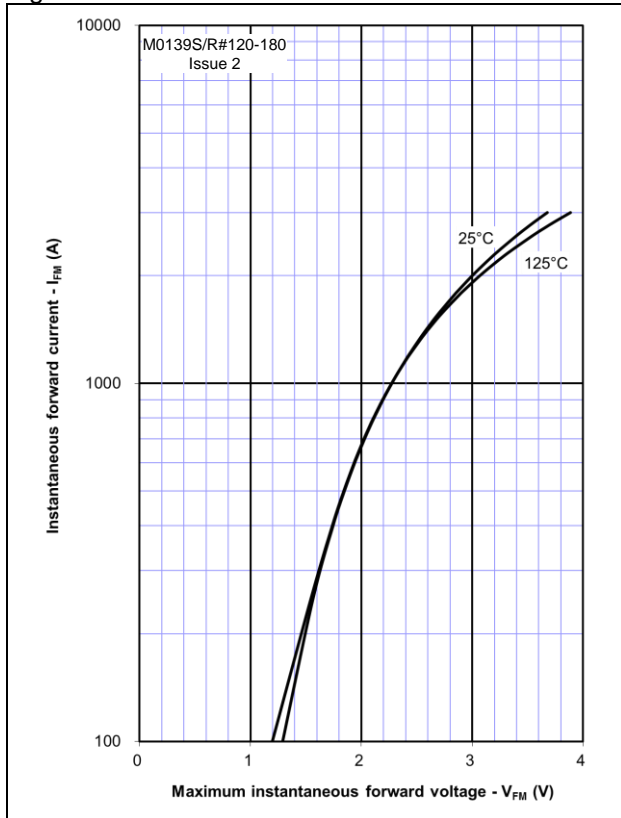


Figure 2 – Recovered charge, Q_{ra} (50% chord)

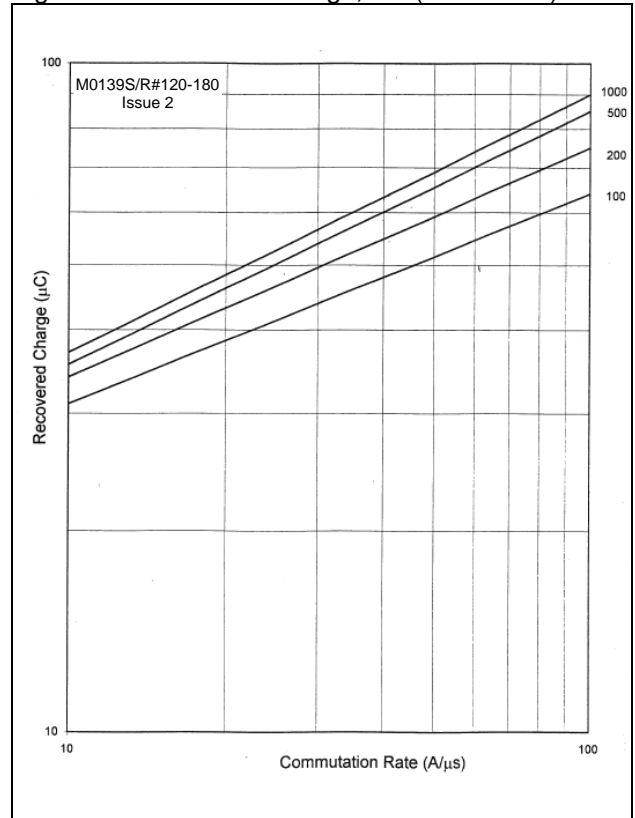


Figure 3 - Reverse recovery energy per pulse

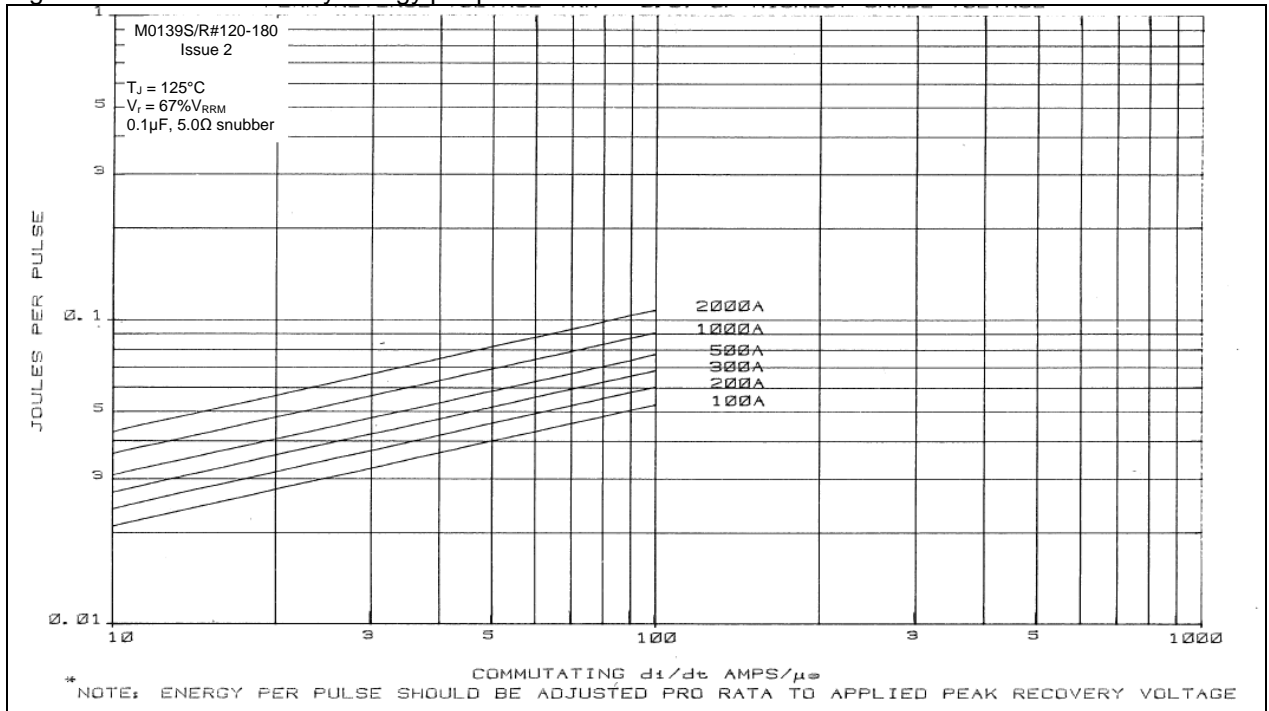


Figure 4 - Sine wave energy per pulse

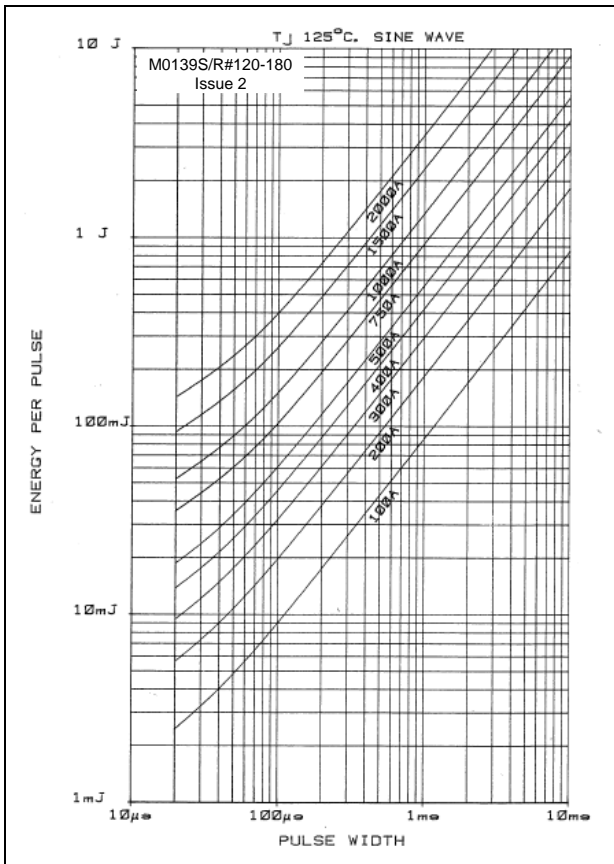


Figure 5 - Sine wave frequency vs. pulse width, T_{case} - 60°C

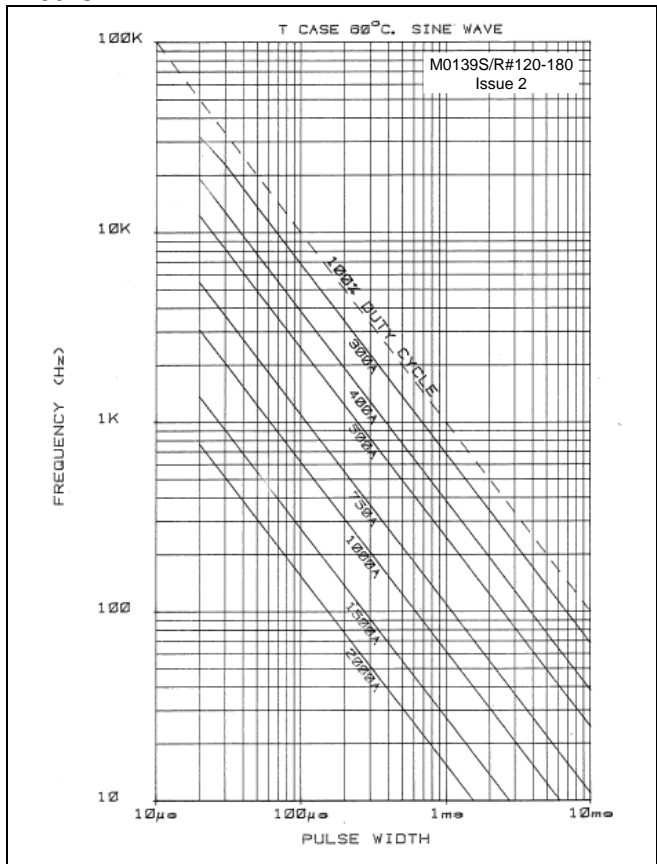


Figure 6 - Sine wave frequency vs. pulse width, T_{case} - 90°C

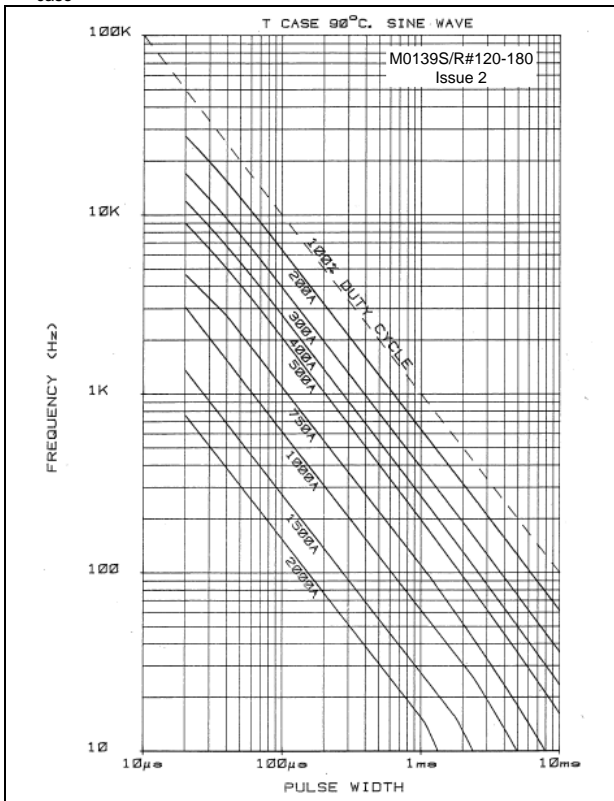


Figure 7 - Square wave energy per pulse, T_J - 125°C, di/dt - 50A/µs

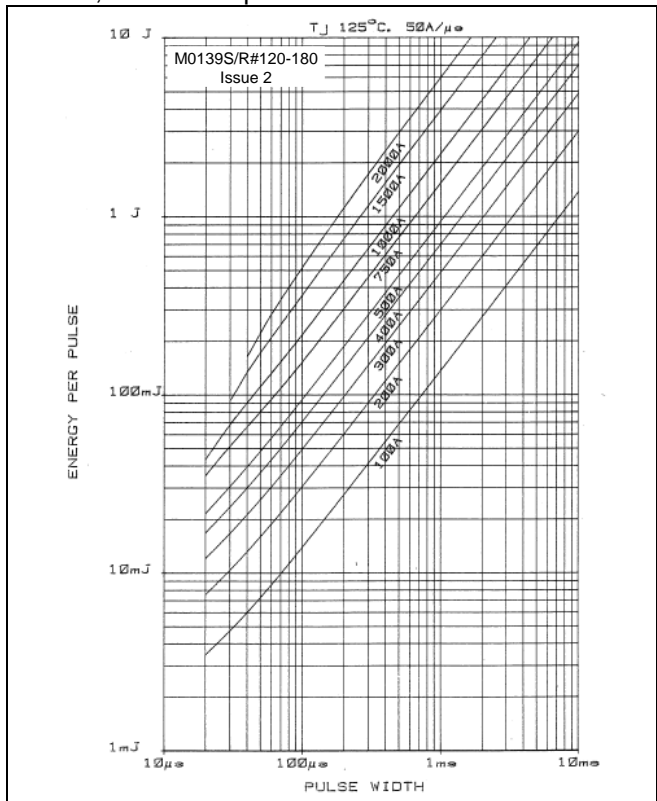


Figure 8 - Square wave energy per pulse, $T_J - 125^\circ\text{C}$, $di/dt - 100\text{A}/\mu\text{s}$

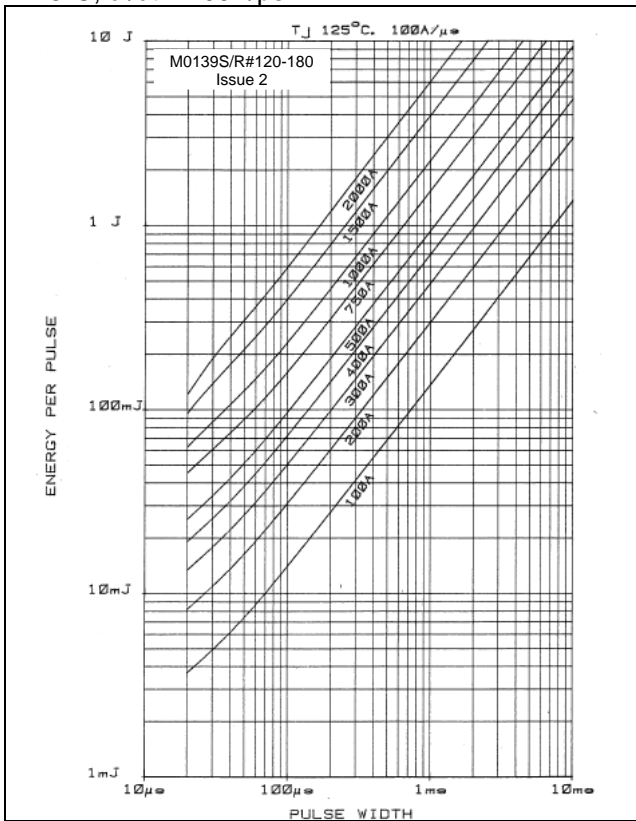


Figure 9 - Square wave frequency vs. pulse width, $T_{\text{case}} - 60^\circ\text{C}$, $di/dt - 50\text{A}/\mu\text{s}$

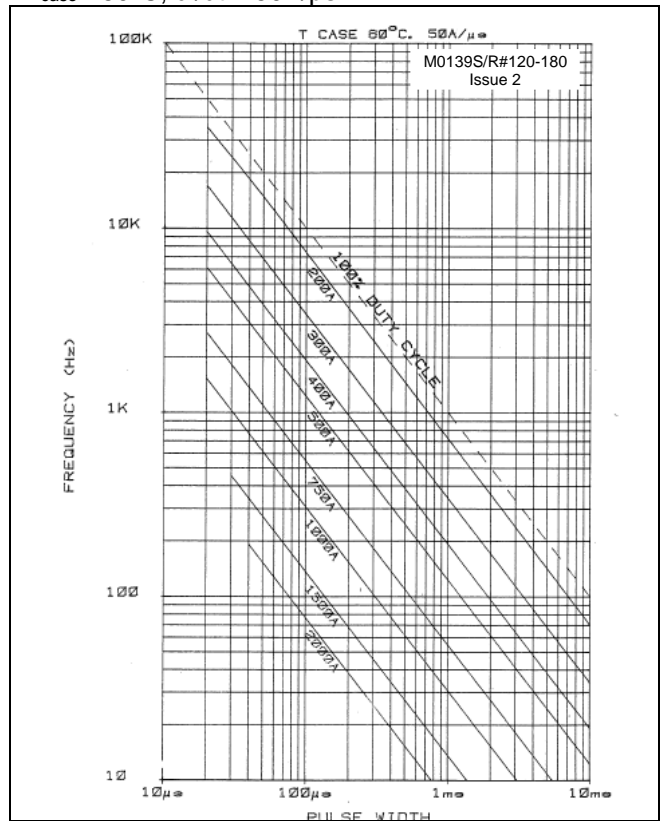


Figure 10 - Square wave frequency vs. pulse width, $T_{\text{case}} - 90^\circ\text{C}$, $di/dt - 50\text{A}/\mu\text{s}$

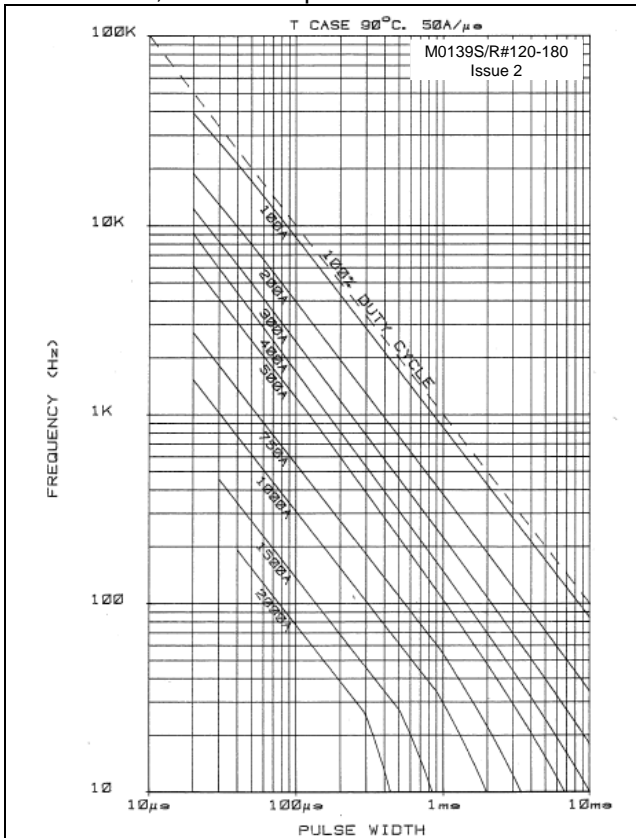


Figure 11 - Square wave frequency vs. pulse width, $T_{\text{case}} - 60^\circ\text{C}$, $di/dt - 100\text{A}/\mu\text{s}$

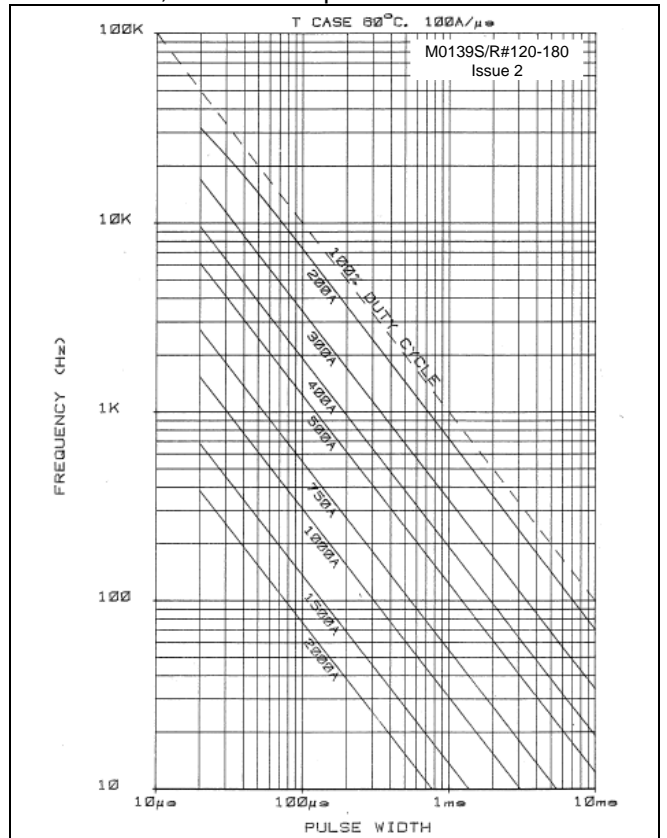


Figure 12 - Square wave frequency vs. pulse width,
 $T_{case} - 90^{\circ}C, di/dt - 100A/\mu s$

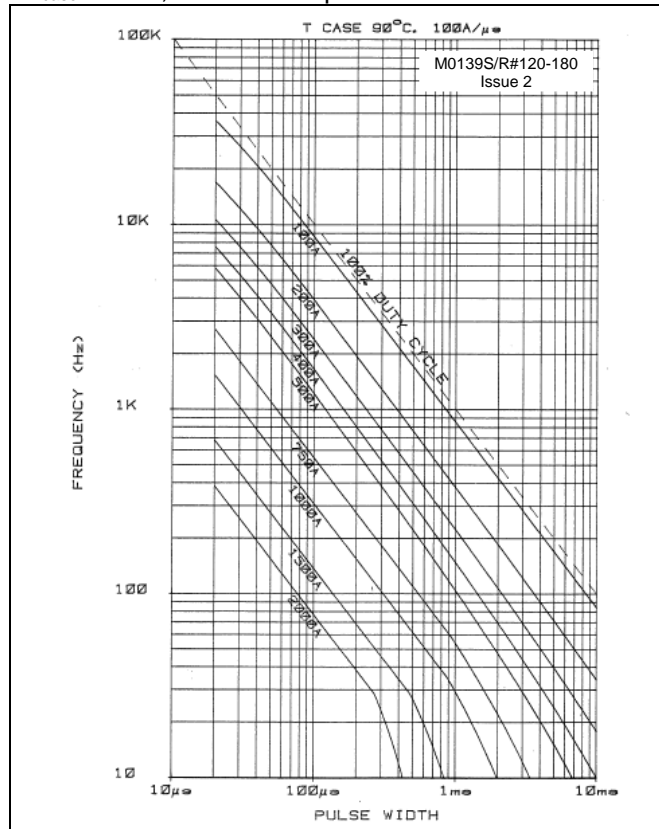


Figure 13 – Maximum surge and I^2t ratings

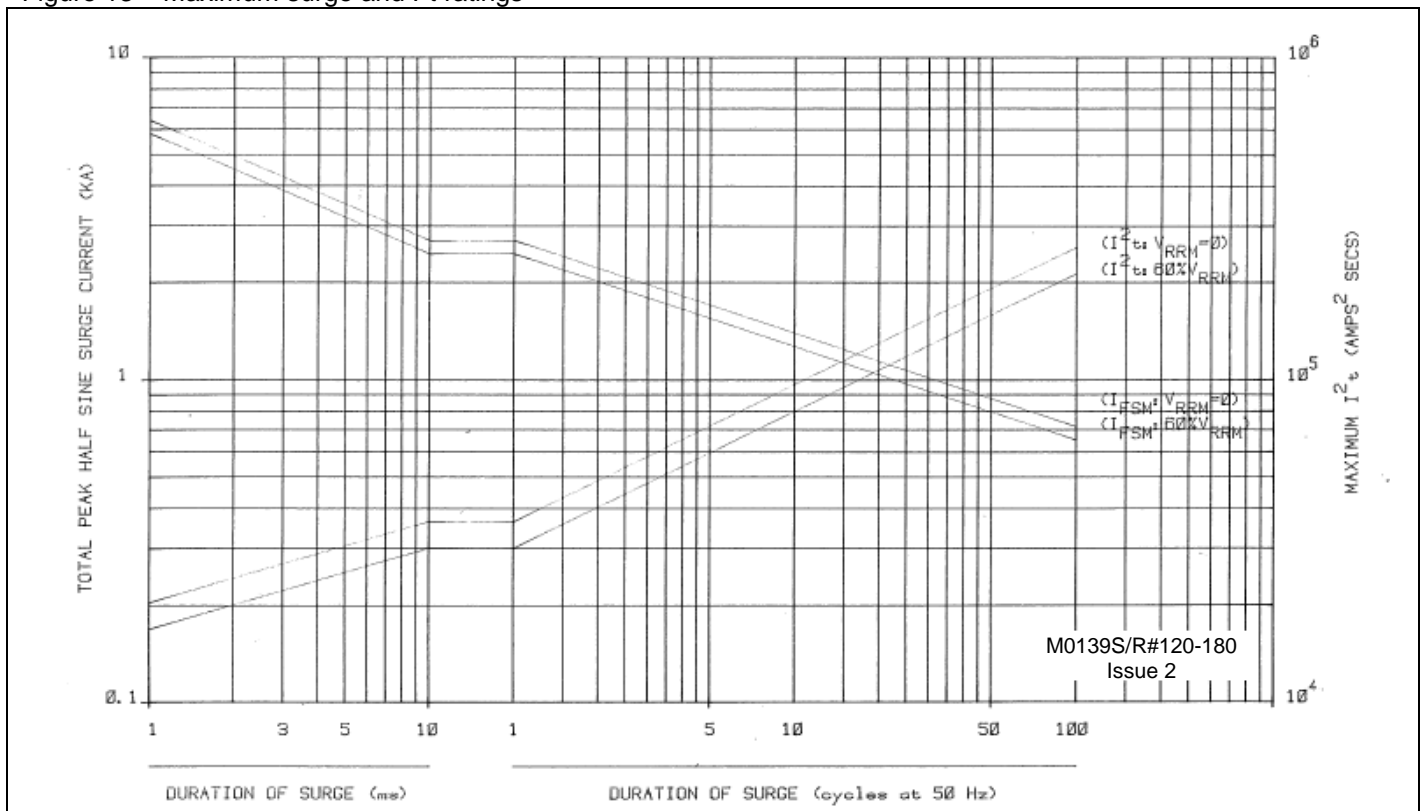
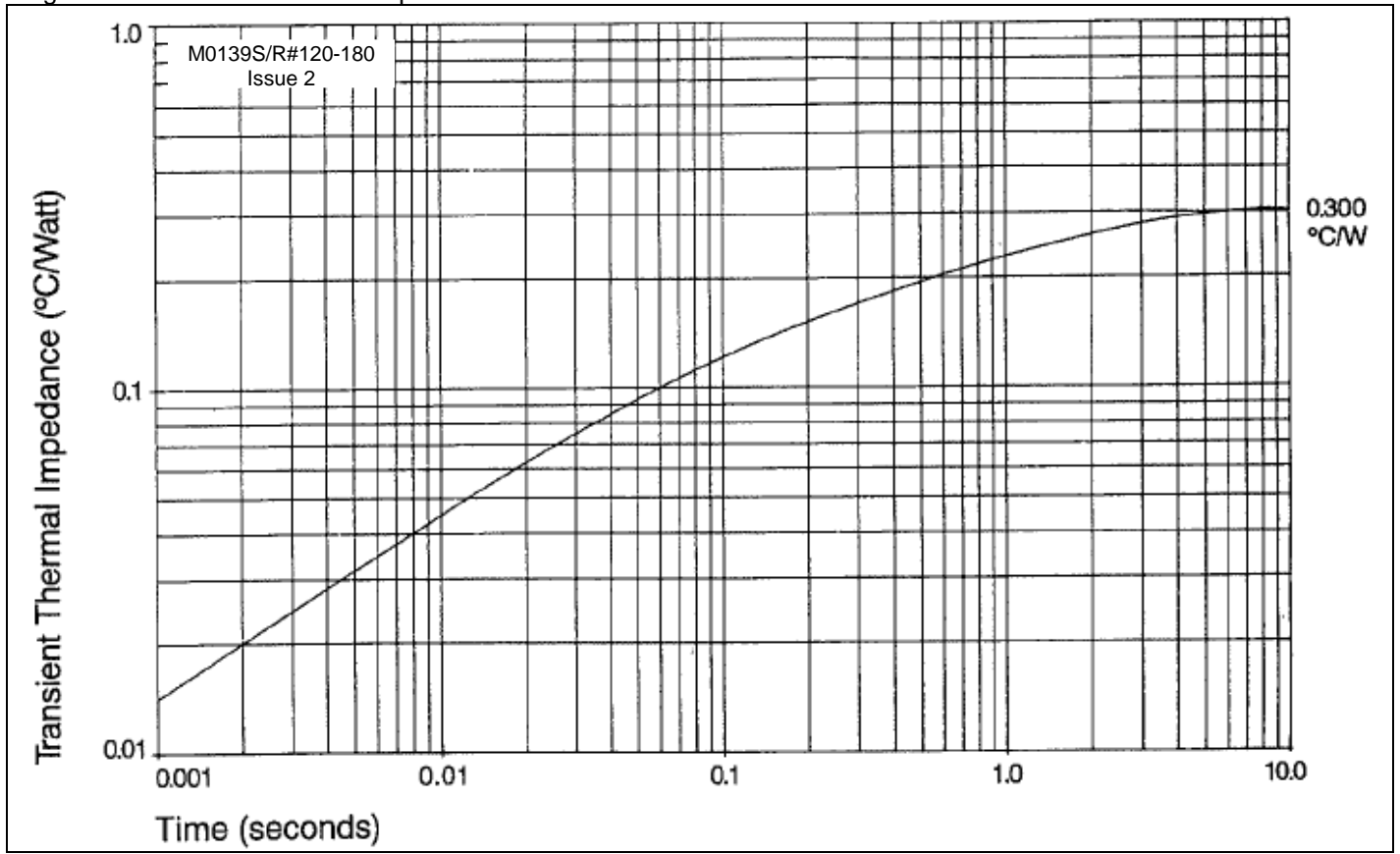
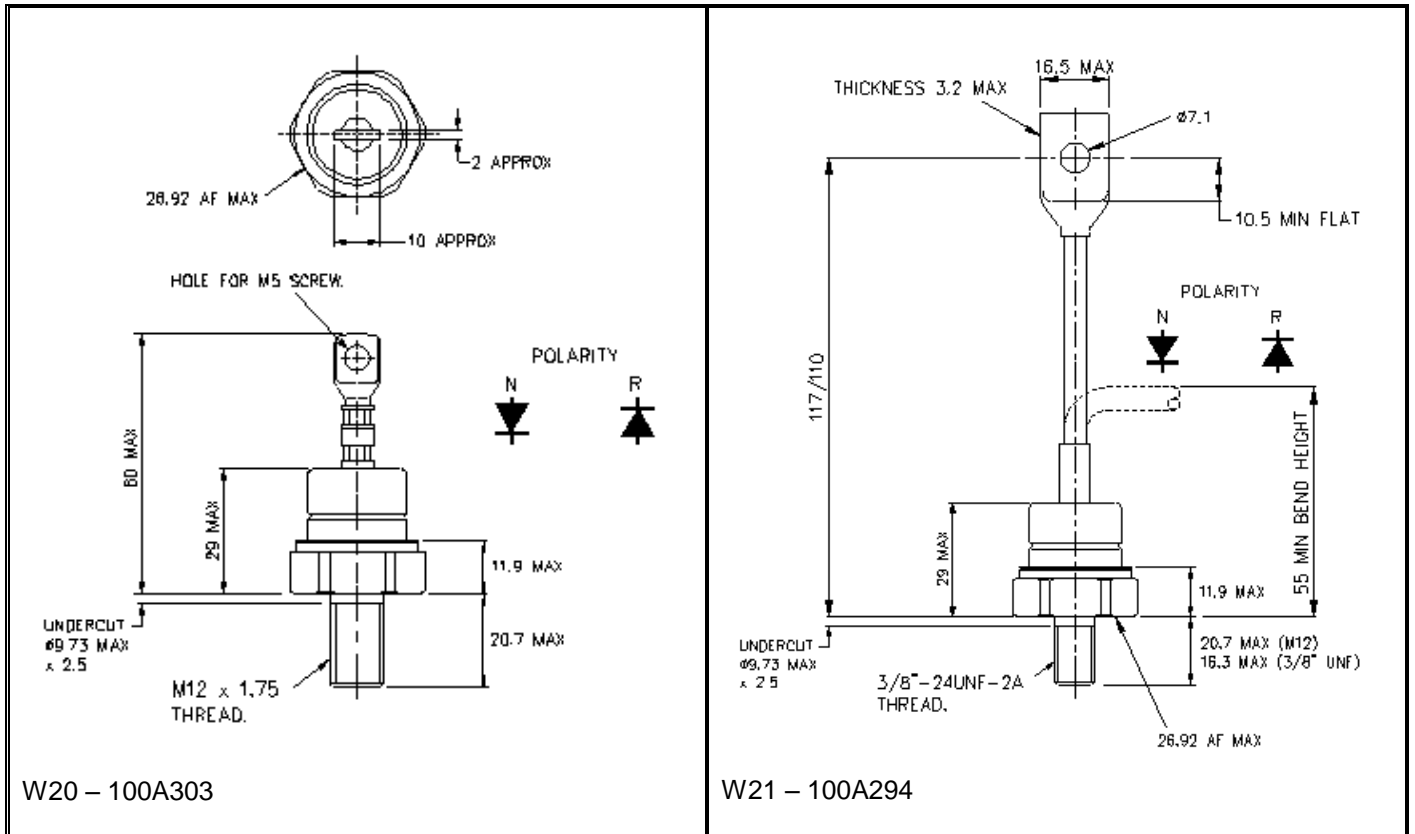


Figure 14 – Transient thermal impedance



Outline Drawing & Ordering Information



ORDERING INFORMATION

(Please quote 10 digit code as below)

| | | | | |
|-----------------|--|---|--|------------|
| M0139 | S/R | # | ◆◆ | 0 |
| Fixed Type Code | Polarity S – Cathode stud R – Anode stud | Fixed outline code L – M12 stud fixing M – 3/8" stud fixing | Voltage code V _{RRM} /100 12-18 | Fixed code |

Order code: M0139RL120 – 1200V V_{RRM}, M12 stud base, stud anode.

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